

66133**3N261****3N262****3N263****TO-18 OPTOCOUPLERS**
**OPTOELECTRONIC PRODUCTS
DIVISION**

01/26/2011

Features:

- High Reliability
- Electrically similar to 4N47, 4N48, 4N49
- Base lead eliminated for improved noise immunity
- Rugged package
- +1 kV electrical isolation
- Stability over wide temperature range

Applications:

- Eliminate ground loops
- Level shifting
- Line receiver
- Switching power supplies
- Motor control

DESCRIPTION

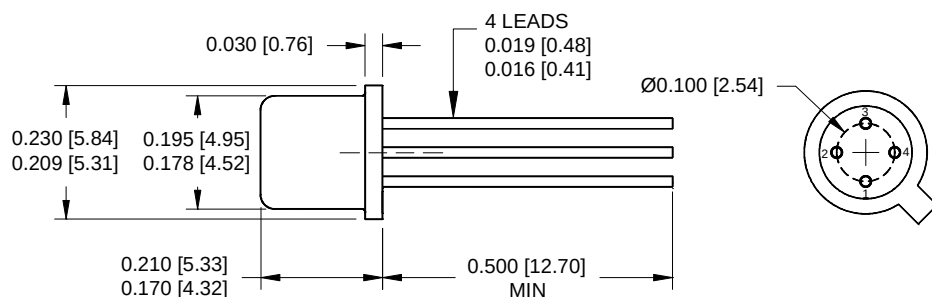
The **66133** contains an infrared LED optically coupled to a silicon phototransistor in a hermetic 4 lead TO-18 package. The collector of the phototransistor is electrically connected to the case. The internal base connection has been eliminated for improved noise immunity. The 3N261, 3N262 and 3N263 can be supplied to commercial or screened quality levels as well as to customer specifications.

ABSOLUTE MAXIMUM RATINGS

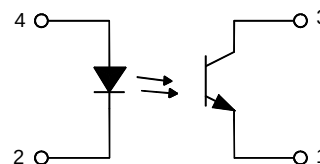
Input to Output Voltage	1000 V
Emitter-Collector Voltage	7 V
Collector-Emitter Voltage	40 V
Reverse Input Voltage	2 V
Input Diode Continuous Forward Current at (or below) 65°C Free-Air Temperature (see note 1)	40 mA
Continuous Collector Current	20 mA
Continuous Transistor Power Dissipation at (or below) 25°C Free-Air Temperature (see Note 2)	190 mW
Storage Temperature	-55°C to +150°C
Operating Free-Air Temperature Range.	-55°C to +125°C
Lead Solder Temperature (10 seconds max, 1/16" from case)	240°C

Notes:

1. Derate linearly to 125°C free-air temperature at the rate of 0.67 mA/°C.
2. Derate linearly to 125°C free-air temperature at the rate of 1.9 mW/°C.

Package Dimensions

ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]

Schematic Diagram

THE COLLECTOR IS IN ELECTRICAL CONTACT WITH THE CASE.

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ELECTRICAL CHARACTERISTICS

INPUT LED

$T_A = 25^\circ\text{C}$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode Static Reverse Current	I_R			100	nA	$V_R = 2\text{ V}$
Input Diode Static Forward Voltage	V_F	0.8		1.5	V	$I_F = 10\text{ mA}$

OUTPUT TRANSISTOR

$T_A = 25^\circ\text{C}$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	40			V	$I_C = 1\text{ mA}$, $I_F = 0$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	7			V	$I_E = 100\text{ }\mu\text{A}$, $I_F = 0$
Collector Dark Current	I_D			100	nA	$V_{CE} = 20\text{ V}$, $I_F = 0\text{ mA}$

COUPLED CHARACTERISTICS

$T_A = 25^\circ\text{C}$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
On State Collector Current 3N261	$I_{C(ON)}$	0.5			mA	$V_{CE} = 5\text{ V}$, $I_F = 1\text{ mA}$
On State Collector Current 3N262	$I_{C(ON)}$	1			mA	$V_{CE} = 5\text{ V}$, $I_F = 1\text{ mA}$
On State Collector Current 3N263	$I_{C(ON)}$	2			mA	$V_{CE} = 5\text{ V}$, $I_F = 1\text{ mA}$
Collector-Emitter Saturation Voltage 3N261 3N262 3N263	$V_{CE(SAT)}$			0.3 0.3 0.3	V	$I_F = 2\text{ mA}$, $I_C = 0.5\text{ mA}$ $I_F = 2\text{ mA}$, $I_C = 1\text{ mA}$ $I_F = 2\text{ mA}$, $I_C = 2\text{ mA}$
Rise Time 3N261 3N262 3N263	t_r		10 10 15	20 20 25	μs	$V_{CE} = 10\text{ V}$, $I_F = 5\text{ mA}$, $R_L = 100\text{ }\Omega$
Fall Time 3N261 3N262 3N263	t_f		10 10 15	20 20 25	μs	$V_{CE} = 10\text{ V}$, $I_F = 5\text{ mA}$, $R_L = 100\text{ }\Omega$
DC Isolation Voltage	V_{IO}	1000			V	$I_{IO} = 100\text{ nA}$

RECOMMENDED OPERATING CONDITIONS:

PARAMETER	SYMBOL	MIN	MAX	UNITS
Input Current, Low Level	I_{FL}	0	10	μA
Input Current, High Level	I_{FH}	1	20	mA
Supply Voltage	V_{CE}	5	10	V

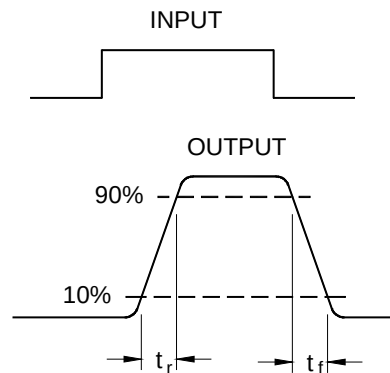
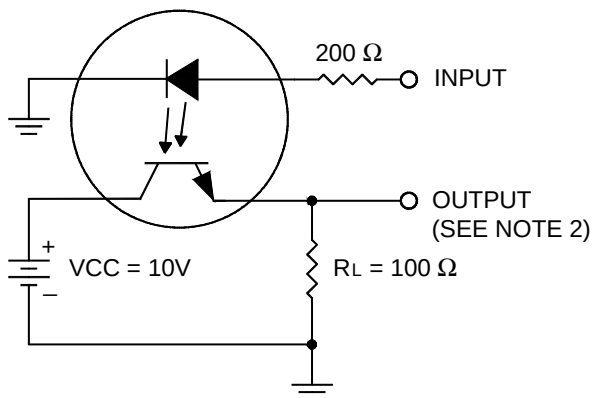
SELECTION GUIDE

PART NUMBER	PART DESCRIPTION
66133-001	3N261, Commercial
66133-002	3N262, Commercial
66133-003	3N263, Commercial
66133-101	3N261R, Screened
66133-102	3N262R, Screened
66133-103	3N263R, Screened

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PARAMETER MEASUREMENT INFORMATION

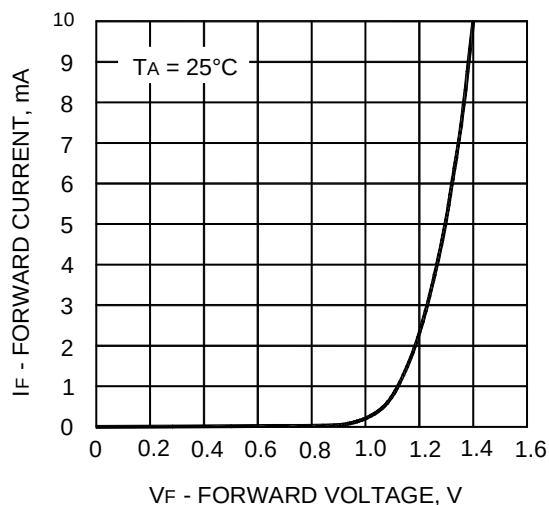
ADJUST AMPLITUDE OF INPUT PULSE FOR $I_{F(ON)} = 5 \text{ mA}$



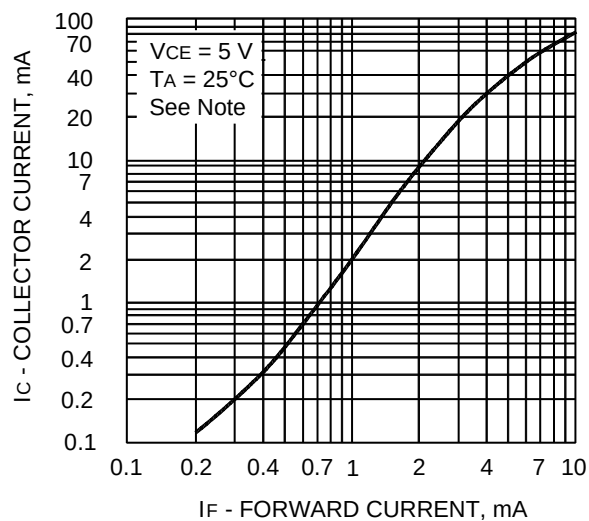
- NOTES:
1. The input waveform is supplied by a generator with the following characteristics: $Z_{OUT} = 50 \Omega$, $t_r \leq 15 \text{ ns}$, Duty cycle $\approx 1\%$, $t_w = 100 \mu\text{s}$.
 2. Waveforms are monitored on an oscilloscope with the following characteristics: $t_r \leq 12 \text{ ns}$, $R_{IN} \geq 1 \text{ M}\Omega$, $C_{IN} \leq 20 \text{ pF}$

TYPICAL CHARACTERISTICS

INPUT DIODE FORWARD CONDUCTION CHARACTERISTICS



3N262
COLLECTOR CURRENT
vs
INPUT DIODE FORWARD CURRENT



NOTE: This parameter was measured using pulse techniques. $t_w = 100 \mu\text{s}$, duty cycle = 1%.

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TYPICAL CHARACTERISTICS (CONTINUED)

